TOSHIBA Photocoupler Photo Relay

TLP594G

Modems

PBXes

Telecommunications

The TOSHIBA TLP594G consists of a gallium arsenide infrared emitting diode optically coupled to a photo–MOS FET in a DIP (DIP6), which is suitable for equipment for high tech communications, including modems. The TLP594G complies with FCC part 68 rules with current limiting function.

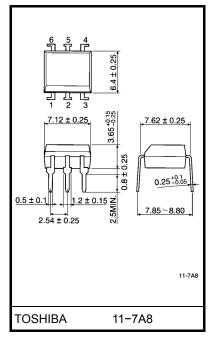
Peak off-state voltage: 350V (min.)
 Trigger LED current: 3mA (max)

• On-state current: 120mA(max)

• Load current limiting: 150mA~300mA (t = 5ms)

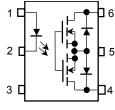
On-state resistance: 35Ω (max)
Isolation voltage: 2500Vrms (min)
UL recognized: UL1577, file no.E67349

Unit in mm



Weight: 0.4g

Pin Configurations (top view)



1 : Anode

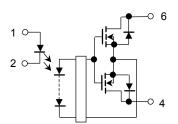
2 : Cathode

3: NC

4 : Drain D1

6 : Drain D2

Schematic



Absolute Maximum Ratings (Ta = 25°C)

	Characteristic	Symbol	Rating	Unit
	Forward current	lF	50	mA
ED	Forward current derating (Ta ≥ 25°C)	ΔI _F / °C	-0.5	mA / °C
	Pulse forward current (100µs pulse, 100pps)	I _{FP}	1	Α
	Reverse voltage	V _R	5	V
	Junction temperature	Tj	125	°C
	Off-state output terminal voltage	V _{OFF}	350	V
Detector	On-state RMS current	I _{ON}	120	mA
	On–state current derating (Ta ≥ 25°C)	ΔI _{ON} / °C	-1.2	mA / °C
	Junction temperature	Tj	125	°C
Storage temperature range		T _{stg}	<i>–</i> 55∼125	°C
Оре	erating temperature range	T _{opr}	−40~85	°C
Lea	d soldering temperature (10 s)	T _{sol}	260	°C
Isola	ation voltage (AC, 1 min., R.H.≤ 60%) (Note 1)	BVS	2500	Vrms

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

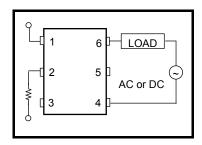
(Note 1): Device considered a two–terminal device: Pins1, 2 and 3 shorted together and pins4, 5 and 6 shorted together.

Recommended Operating Conditions

Characteristics	Symbol	Min	Тур.	Max	Unit
Supply voltage	V_{DD}	_	_	280	V
Forward current	lF	5	7.5	25	mA
On-state current	I _{ON}	_	_	120	mA
Operating temperature	T _{opr}	-20	_	65	°C

Note: Recommended operating conditions are given as a design guideline to obtain expected performance of the device. Additionally, each item is an independent guideline respectively. In developing designs using this product, please confirm specified characteristics shown in this document.

Circuit Connections



Individual Electrical Characteristics (Ta = 25°C)

	Characteristic	Symbol	Test Condition	Min	Тур.	Max	Unit
	Forward voltage	V_{F}	I _F = 10mA	1.0	1.15	1.3	V
ED	Reverse current	I _R	V _R = 5V	_	_	10	μΑ
	Capacitance	C _T	V = 0, f = 1MHz	_	30	_	pF
ctor	Off-state current	I _{OFF}	V _{OFF} = 350V	-	_	1	μΑ
Detector	Capacitance	C _{OFF}	V = 0, f = 1MHz	_	40	_	pF

Coupled Electrical Characteristics (Ta = 25°C)

Characteristic	Symbol	Test Condition	Mln	Тур.	Max	Unit
Trigger LED current	I _{FT}	I _{ON} = 120mA	_	_	3	mA
On–state resistance	R _{ON}	I _{ON} = 120mA, I _F = 5mA	_	22	35	Ω
OII-state resistance		I _{ON} = 20~120mA, I _F = 5mA	1	26	40	Ω
Load current limiting	I _{LIM}	$I_F = 5mA, V_{DD} = 5V, t = 5ms$	150	_	300	mA

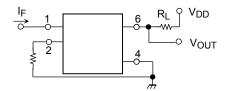
Isolation Characteristics (Ta = 25°C)

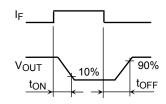
Characteristic	Symbol	Test Condition	Min	Тур.	Max	Unit
Capacitance input to output	Cs	V _S = 0, f = 1 MHz	_	0.8	_	pF
Isolation resistance	R _S	V _S = 500 V, R.H. ≤ 60%	5×10 ¹⁰	10 ¹⁴	-	Ω
	BVS	AC, 1 minute	2500	_	-	Vrms
Isolation voltage		AC, 1 second, in oil	_	5000	-	
		DC, 1 minute, in oil	_	5000	_	Vdc

Switching Characteristics (Ta = 25°C)

Characteristic	Symbol	Test Condition	Min	Тур.	Max	Unit
Turn-on time	ton	$R_L = 200\Omega$ (Note2)	_	_	1	ms
Turn-off time	tOFF	$V_{DD} = 20V, I_F = 5mA$	_	_	1	1113

(Note2): Switching time test circuit





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20070701-EN

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